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				Application Number		09/412,512
				Filing Date		October 5, 1999
				First Named Inventor		Shunpei YAMAZAKI
				Group Art Unit		2812
				Examiner Name		R. Booth
Sheet 1 of 1				Attorney Docket Number		0756-2046

U.S. PATENT DOCUMENTS						
Examiner Initials ⁵	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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FOREIGN PATENT DOCUMENTS								
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
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RA		U.S. Patent Application Serial No. 09/352,194, including Specification, Drawings, Pending Claims and Pending Office Action, "Crystalline Semiconductor Thin Film, Method of Fabricating the Same Semiconductor Device, and Method of Fabricating the Same", Shunpei Yamazaki et al., July 13, 1999.	
RA		U.S. Patent Application Serial No. 09/894,125, including Specification, Drawings Pending Claims and Pending Office Action, "Crystalline Semiconductor Thin Film, Method of Fabricating the Same Semiconductor Device, and Method of Fabricating the Same", Shunpei Yamazaki et al., June 29, 2001.	

Examiner Signature		Date Considered	9/16/02
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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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